# (Autonomous Institution – UGC, Govt. of India) UG Model question paper

		Model question paper	
Time:	3 hours	Engineering Physics	Max Marks: 70
Note:	This question paper contains	of 5 sections. Answer five questions, cho	osing one
	on from each section and each		G
1		Section-I	
1	a) Derive an expression for co		[10M]
1.	b) Explain the formation of c		[4M]
	b) Explain the formation of C	Svalent bond in a sond.	[דויו]
		OR	
2.	a) Explain with neat diagram	s the 7 crystal systems and 14 Bravais L	attices. [9M]
	b) What are Miller Indices an	d explain a procedure to find Miller indi	ices for a
	crystal plane.	•	[5M]
	7 1	Section-II	
3.	a) State and explain Bragg's I		[6M]
٥.		r method can be used for the determinat	
	parameters.	method can be used for the determinat	[8M]
	parameters.	OR	[OM]
4	200	_	
4.	-	imate the concentration of frenkel defec	
	at any giventemperature.		[10M]
	b) What is Burger's vector? E	•	[4M]
		Section-III	
5.	a)Derive an expression for el	ectronic and ionic polarization of dielect	tric material.
			[10M]
	b) Derive the Classius - Mosso	otti relation.	[4M]
		OR	
6.	a)Define electric susceptibilit	y, polarization vector and electric displa	acement vector.
		y, F	[4M]
	h) Derive an expression for in	ternal field in a dielectric material with	
	where needed.	ternar nera in a arefective material with	[10M]
	where needed.	Section-IV	[TOM]
7	a) Dariya an aymrassian for P		[MO]
7.	,		[8M]
	b) What is Meissner effect? E	•	[6M]
	3.77	OR	50.47
8.	<i>y</i> 1	•	[8M]
	b) What is hysteresis and exp	plain the Hysteresis loop on the basis of	domain theory.
			[6M]
Section-V			
9.	a) Discuss about the origin fo	r nanotechnology.	[6M]
	b) Explain the synthesis of na	ano materials by sol-gel technique.	[8M]
		OR	
10	. a) Explain in brief the SEM te	chniques of nano material characterizat	tion. [9M]
_0	b) Give some applications of	_	[5M]
	2, arre come applications of		[01.1]

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Time: 3 hours	<b>Engineering Physics</b>	Max Marks: 70
<b>Note:</b> This question paper contains of 5 sections. Answer five questions, choosing one question from each section and each question carries 14 marks.		
	Section-I	
-	uilibrium spacing of two atoms and also phesive energy of a diatomic molecule. <b>OR</b>	o derive an expression [14M]
2. Discuss about seven crystal Sketchs	systems and their corresponding Bravi	ias Lattices with neat [14M]
	Section-II	
determination of crystal s b) X -rays of wave length 1	v diffraction and describe powder diffra structure. 1.5418 A <sup>0</sup> are diffracted by (1 1 1) plane alculate the inter atomic spacing of the <b>OR</b>	[10M] es in a crystal at angle of
<ul><li>4. a) Derive an expression for</li><li>b) Explain the significance of</li></ul>	the concentration of Schottky defect in	an ionic crystal. [10M] [4M]
	Section-III	
<ul><li>5. a) Derive an expression for o</li><li>b) Derive the Classius –Mos</li></ul>	electronic and ionic polarization of diel sotti relation.	ectric material. [10M] [4M]
( a) Explain Palarization wast	OR	agamtihilitu [4M]
b) What is piezo electricity? c) Give any three application	-	sceptibility. [4M] [4M] [6M]
c) Give any timee application	is of diefectife materials.	[OM]
	Section-IV	
7. a) Differentiate Ferro and A b) Explain Hysteresis loop of	_	[6M] [8M]
<ol><li>a)Discuss Meissner effect</li><li>b)Write about Type I and Type</li></ol>		[6M] [8M]
	Section-V	
	Distinguish Nanoscience and Nanotech s of fabricating nanomaterials.  OR	nology. [6M] [8M]
10. a) Explain how do you use T b) Mention any five applica	TEM to characterize nonoparicles. ations of nanomaterials.	[6M] [8M]

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<b>Note:</b> This question paper contains of 5 sections. Answer five questions, choosing one question from each section and each question carries 14 marks. <b>Section-I</b>				
1.	<ul><li>a) Deduce an expression for</li><li>b) Explain brief about prima</li></ul>	r cohesive energy between two atoms f	orming a bond.	[10M] [4M]
		OR		
	-	thest packing fraction of the three cubic es and explain a procedure to find Mille		[7M] Il plane. [7M]
		Section-II		
3.	<ul><li>a) Derive an expression to es</li><li>b) What is Burger's vector?</li></ul>	stimate the concentration of Schottky Explain.	defects.	[10M] [4M]
		OR		
4.	a) Discuss how X-ray powder	method can be used for the determina	ition of crystal param	neters. [8M]
	b) For a cubic crystal with la (1 0 1) amd (2 1 1)	ttice parameter 'a' find the inter – plan	ar spacing for planes	(2 3 1), [6M]
_		Section-III	_	
5.	<ul><li>a) Derive an expression for e</li><li>b) Write the applications of o</li></ul>		naterial.	[10M] [4M]
_	a) Obtain an armanaire for t	OR	work- Field)	[10][1
	•	the internal field of cubic structure (Lo pility of a dielectric gas having dielectri Section-IV	•	[10M] 41[4M]
7.	a) Differentiate Dia, Para, Fe	rro magnetic materials with neat diagr	ams where needed.	[6M]
	b) Differentiate hard and sof	t magnetic material.		[5M]
	c) Explain the terms Magneti	ization, Retentivity and Coercivity. <b>OR</b>		[3M]
8.	a) What is Meissner effect? E	-		[7M]
	b) Describe the difference be	etween Type-I and Type – II super con <b>Section-V</b>	ductors.	[7M]
	a) Explain the preparation of	8		[6M]
	<ul><li>b) Discuss about surface to v</li><li>c) Explain the classification of</li></ul>	rolume ratio of nano materials. of nano materials.		[4M] [4M]
OR				
10.	a) What is Quantum confine			[4M]
	-	tion of nano particles by SEM and TEM		[8M] [2M]

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Max Marks: 70

**Engineering Physics** 

Time: 3 hours

<b>Note:</b> This question paper contains of 5 sections. Answer five questions, choosing one			
question from each section and each question carries 14 marks.			
- •			
Section-I			
1. a) What are secondary bonds and explain each of them?	[7M]		
b) What is cohesive energy and obtain an expression for cohesive energy showing			
graphically the variation of attractive and repulsive potential energy with respe	ct to inter		
atomic distance?	[7M]		
OR			
2. a) What are Bravais lattice? Describe them in combination with crystal systems?	[5M]		
b) Calculate the co ordination number and APF in case of FCC structure?	[4M]		
c) Derive an expression for inter planar distance between two successive planes?	[5M]		
Section-II			
3. a) What is Bragg's law of X-ray diffraction? Explain?	[4M]		
b) Describe in detail powder method to determine the crystal structure?	[6M]		
c) A beam of X-rays is incident on an ionic crystal with lattice spacing 0.313 nm. (	Calculate		
the wavelength of X-rays if the first order Bragg reflection takes place at a glan	cing angle		
70481.	[4M]		
OR			
4. a) What is Burger vector? In what direction do the Burger vector lie with respect	to i. An		
Edge dislocation ii. Screw dislocation?	[7M]		
b) Derive an expression for concentration of Frenkel defect in an ionic crystal?	[7M]		
Section-III			
5. a) Obtain the relevant mathematical expression for i. Electronic polarizability and	ii Ionic		
polarizability?	[7M]		
b) What is internal field and Derive an expression for calculation of internal field in			
dielectric material? [7M]			
	[, , , , ]		
OR			
6. a) Distinguish between Ferro- electricity and Piezo – electricity?	[7M]		
b) Derive Classius- Mosotti relation?	[7M]		
Section-IV			
7. a) Define the terms magnetic induction (B), magnetization (M) and magnetic field (H).			
Obtain an expression relating to those quantities?	[7M]		
b) Explain, in detail, the hysteresis of a ferromagnetic material?	[7M]		
O.D.			
OR  9. a) Distinguish between diamagnetic and paramagnetic materials?	[4 ]		
8. a) Distinguish between diamagnetic and paramagnetic materials? b) Super conductors exhibits perfect diamagnetism. Explain?	[4 M]		
b) Super conductors exhibits perfect diamagnetism- Explain?	[6M]		
c) Discuss the applications of super conductor?	[4M]		

### **Section-V**

9.	0. a) Write notes on:		
	i. Nano scale ii. Quantum confinement and iii. Surface to volume ratio?		

b) Describe the processes of "physical vapour deposition" in the fabrication of nano structures? [7M]

[7M]

### OR

10. a) Describe the processes of Sol Gel method in the fabrication of nano structures?[7M]

b) Explain how TEM can be used to characterize nano particles? [7M]

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Ti	me: 3 hours	Engineering Physics	Max Marks: 70
		s of 5 sections. Answer five questions, choosi	
	from each section and each		and direction
		Section-I	
1.	a) Derive an expression for mir	nimum potential energy of a molecule?	[7M]
	b) Explain the formation of Ion	<u>-</u>	[7M]
_		OR	
2.	a) Show that FCC is the most clopacking factors?	osely packed of the three cubic structures by	working out the [8M]
	b) Define Miller-indices. Sketch (010),(110) and (111).	the following atomic planes in a simple cubi	ic structure [ <b>6M]</b>
		Section-II	
3.	a) Describe with a suitable diag	gram, the powder method for the determinat	ion of crystal
	structure.		[8 M]
	b) Derive Bragg's law of X-ray of	•	[6M]
		OR	
4.		centration of Frenkel defect in an ionic cryst	
	b) Write notes on 'point defects	s in crystais.	[4M]
		Section-III	
5.	a) Define the following terms i)	Electric susceptibility ii) Electric polarization	n iii)Dielectric
	constant?	, .	[4M]
	b) Describe Lorentz method to	calculate the internal field of a cubic structure	re? <b>[10M]</b>
_		OR	
6.	· ·	zability in atoms and obtain an expression fo	
	polarizability in terms of the		[8M]
	b) Explain Gausius-Mosotti lei	ation in dielectrics subjected to static field.	[6M]
Section-IV			
7.	a) Define magnetic moment? E	xplain origin of magnetic moment at the ator	mic level.
			[7M]
	b) Explain the hysteresis loop of	observed in Ferro-magnetic materials.	[7M]
OR			
8.	a) What is Meissner effect? Exp		[6M]
	b) Explain domain theory of Fe	rro-magnetism.?	[7M]

# **Section-V**

<ul><li>9. a) Describe the basic principles of nano-materials.</li><li>b) Explain the principle and working of PVD technique?</li></ul>	[4 M] [10M]
OR	
10. a) Explain in detail the sol-gel method to prepare nano-materials?	[10M]
b) Describe the XRD method to characterize nano -materials.?	[4M]